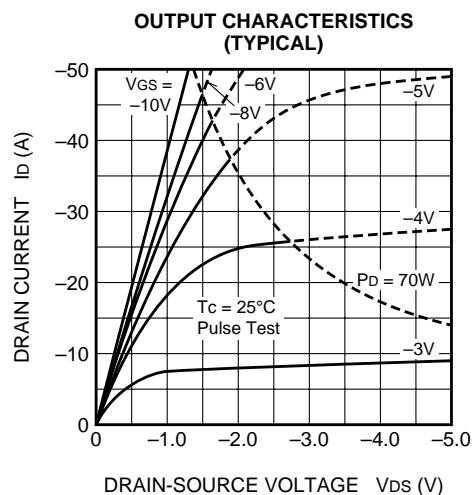
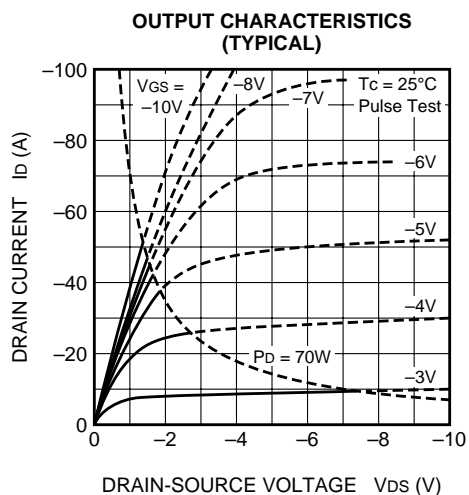
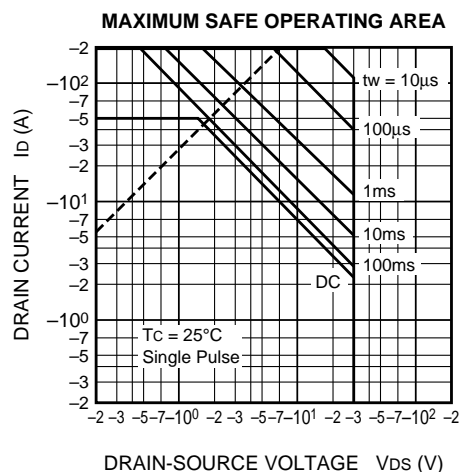
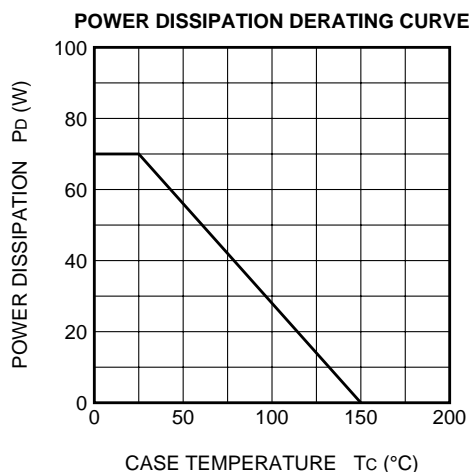


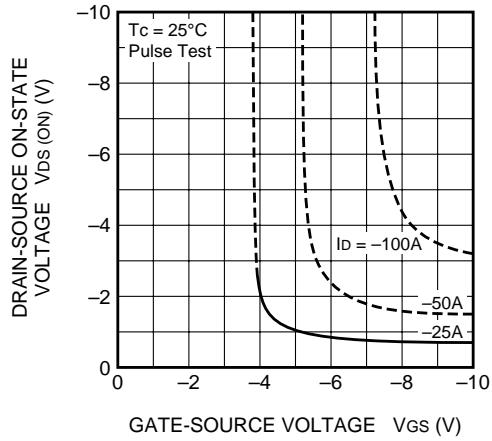
ELECTRICAL CHARACTERISTICS ($T_{ch} = 25^{\circ}\text{C}$)

Symbol	Parameter	Test conditions	Limits			Unit
			Min.	Typ.	Max.	
$V_{(BR)DSS}$	Drain-source breakdown voltage	$I_D = -1\text{mA}$, $V_{DS} = 0\text{V}$	-30	—	—	V
I_{GSS}	Gate-source leakage current	$V_{GS} = \pm 20\text{V}$, $V_{DS} = 0\text{V}$	—	—	± 0.1	μA
I_{DSS}	Drain-source leakage current	$V_{DS} = -30\text{V}$, $V_{GS} = 0\text{V}$	—	—	-0.1	mA
$V_{GS(th)}$	Gate-source threshold voltage	$I_D = -1\text{mA}$, $V_{DS} = -10\text{V}$	-1.3	-1.8	-2.3	V
$r_{DS(on)}$	Drain-source on-state resistance	$I_D = -25\text{A}$, $V_{GS} = -10\text{V}$	—	28	35	$\text{m}\Omega$
$r_{DS(on)}$	Drain-source on-state resistance	$I_D = -9\text{A}$, $V_{GS} = -4\text{V}$	—	54	72	$\text{m}\Omega$
$V_{DS(on)}$	Drain-source on-state voltage	$I_D = -25\text{A}$, $V_{GS} = -10\text{V}$	—	-0.70	-0.88	V
$ y_{fs} $	Forward transfer admittance	$I_D = -25\text{A}$, $V_{DS} = -10\text{V}$	—	23	—	S
C_{iss}	Input capacitance	$V_{DS} = -10\text{V}$, $V_{GS} = 0\text{V}$, $f = 1\text{MHz}$	—	4270	—	pF
C_{oss}	Output capacitance		—	695	—	pF
C_{rss}	Reverse transfer capacitance		—	342	—	pF
$t_d(on)$	Turn-on delay time	$V_{DD} = -15\text{V}$, $I_D = -25\text{A}$, $V_{GS} = -10\text{V}$, $R_{GEN} = R_{GS} = 50\Omega$	—	21	—	ns
t_r	Rise time		—	103	—	ns
$t_d(off)$	Turn-off delay time		—	223	—	ns
t_f	Fall time		—	122	—	ns
V_{SD}	Source-drain voltage	$I_S = -25\text{A}$, $V_{GS} = 0\text{V}$	—	-1.0	-1.5	V
$R_{th(ch-c)}$	Thermal resistance	Channel to case	—	—	1.79	$^{\circ}\text{C/W}$
t_{rr}	Reverse recovery time	$I_S = -25\text{A}$, $di/dt = 50\text{A}/\mu\text{s}$	—	55	—	ns

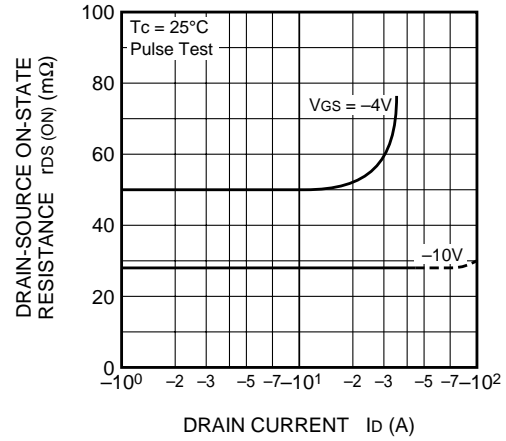
PERFORMANCE CURVES



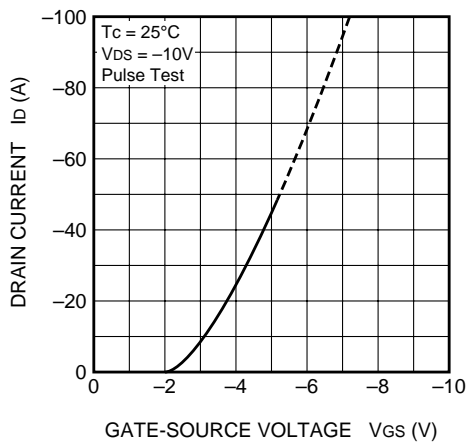
**ON-STATE VOLTAGE VS.
GATE-SOURCE VOLTAGE
(TYPICAL)**



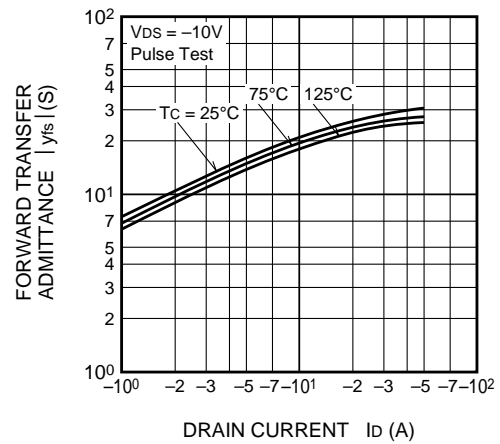
**ON-STATE RESISTANCE VS.
DRAIN CURRENT
(TYPICAL)**



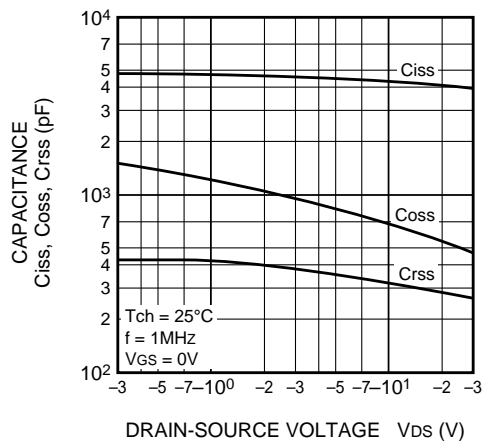
**TRANSFER CHARACTERISTICS
(TYPICAL)**



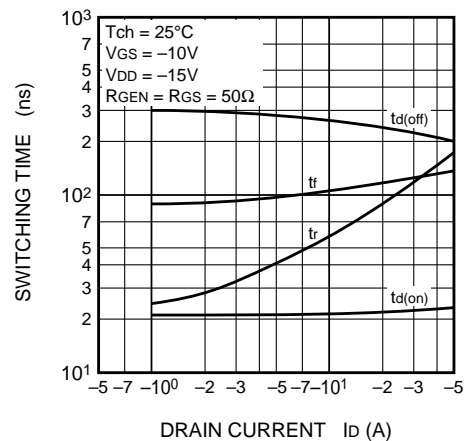
**FORWARD TRANSFER ADMITTANCE
VS. DRAIN CURRENT
(TYPICAL)**



**CAPACITANCE VS.
DRAIN-SOURCE VOLTAGE
(TYPICAL)**



**SWITCHING CHARACTERISTICS
(TYPICAL)**



PRELIMINARY
 Notice: This is not a final specification.
 Some parametric limits are subject to change.

FX50SMJ-03

HIGH-SPEED SWITCHING USE

